

FEATURES

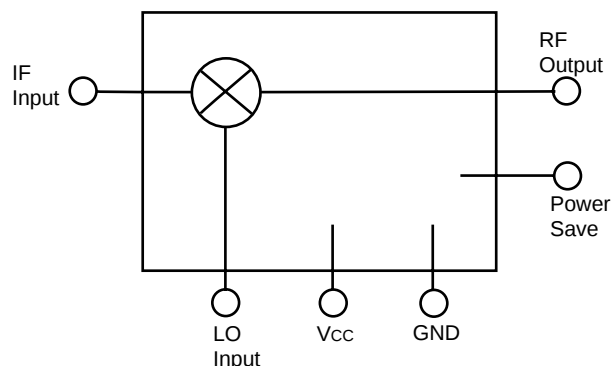
- **WIDE BAND OPERATION:**
IF Input: 3 dB BW: 50 ~ 400 MHz Typical
RF Output: 3 dB BW: 0.1~2 GHz Typical
- **LOW VOLTAGE OPERATION:** 2.7 V Minimum
- **LOW POWER CONSUMPTION:** 15 mW
- **POWER SAVE FUNCTION**
- **SUPER SMALL PACKAGE**
- **TAPE AND REEL PACKAGING OPTION AVAILABLE**

DESCRIPTION

The UPC8109T is an L-Band Frequency Up-Converter manufactured using the NESAT III MMIC process. The UPC8109T was designed for low current consumption. Operation from a 3 volt supply voltage makes this device ideal for handheld cellular, PCN and wireless LAN applications.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.

INTERNAL BLOCK DIAGRAM



ELECTRICAL CHARACTERISTICS (TA = 25°C, VCC = 3 V, fIF = 240 MHz, PLO = -5 dBm, VPS ≥ 2.5V)

PART NUMBER PACKAGE OUTLINE			UPC8109T T06		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
ICC	Circuit Current, VPS ≥ 2.5 V	mA	2.5	5	8
CG	Conversion Gain ¹ , fRF = 900 MHz fRF = 1.9 GHz	dB dB	4 2	7 5	10 8
NF	SSB Noise Figure, fRF = 900 MHz	dB		8.5	
PSAT	Saturated Output Power ² , fRF = 900 MHz fRF = 1.9 GHz	dBm dBm	-7.5 -10	-6 -8	
OIP3	Output 3rd Order Intercept Point ³ , fRF = 900, 900.4 MHz fRF = 1.9, 1.9004 GHz	dBm dBm		+1.5 -1.0	
TPS	Power Save Response Time, VPS : GND → VCC VPS : VCC → GND	μs μs		2.0 2.0	
RTH (J-A)	Thermal Resistance (Junction to Ambient) Free Air Mounted on a 50 x 50 x 1.6 mm epoxy glass PWB	°C/W °C/W			620 230

Notes:

1. PIF = -30 dBm.

2. PIF = -10 dBm.

3. fIF1 = 240.0 MHz, fIF2 = 240.4 MHz

ABSOLUTE MAXIMUM RATINGS¹ (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
V _{CC}	Supply Voltage	V	6.0
V _{PS}	Power Save Voltage	V	6.0
P _T	Total Power Dissipation ²	mW	280
T _{OP}	Operating Temperature	°C	-40 to +85
T _{STG}	Storage Temperature	°C	-55 to +150

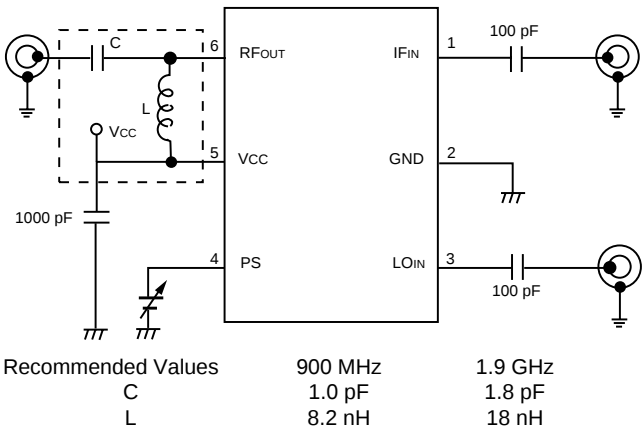
Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.
2. Mounted on a 50 x 50 x 1.6 mm epoxy glass PWB (T_A = +85°C).

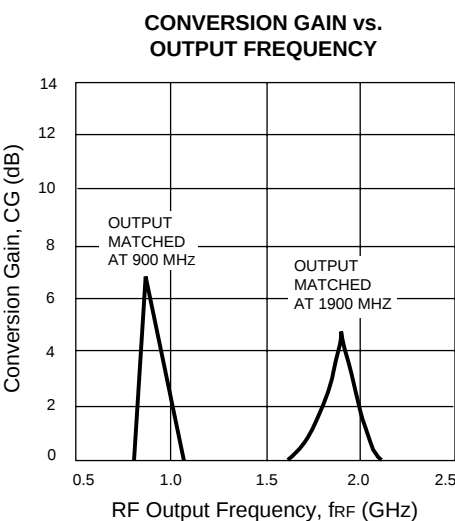
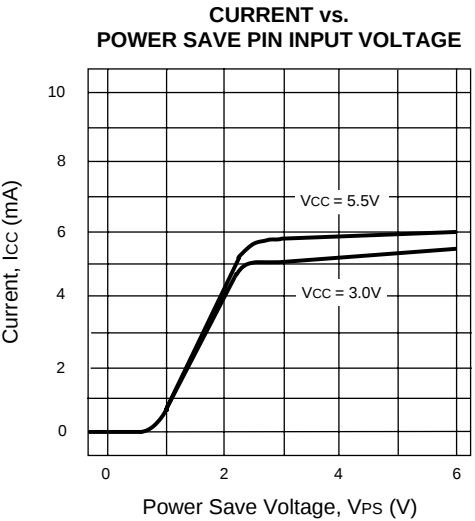
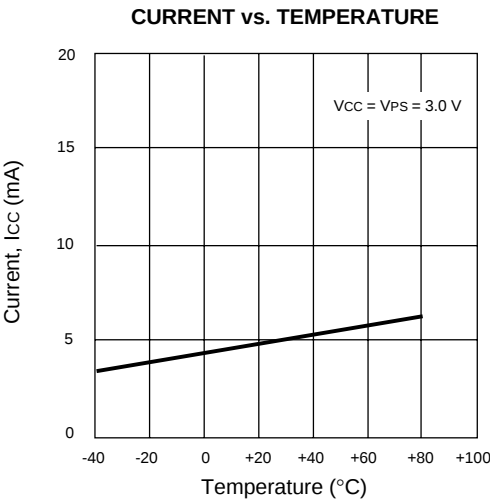
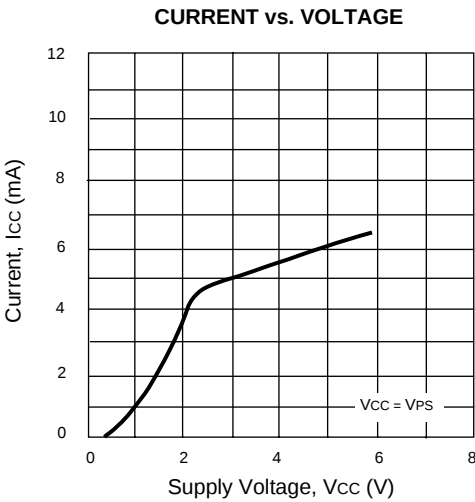
RECOMMENDED
OPERATING CONDITIONS

SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
V _{CC}	Supply Voltage	V	2.7	3.0	5.5
T _{OP}	Operating Temperature	°C	-40	+25	+85
P _{LO}	LO Input Level	dBm	-10	-5	0

TEST CIRCUIT

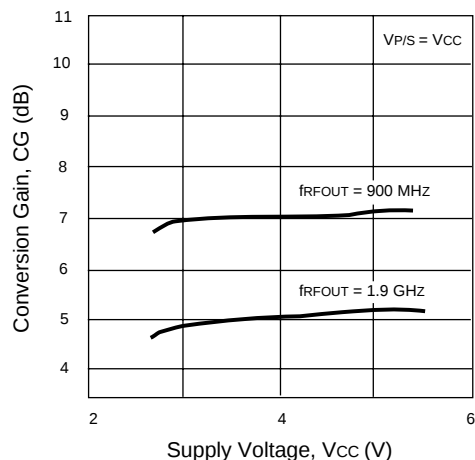


TYPICAL PERFORMANCE CURVES (T_A = 25°C unless otherwise specified)

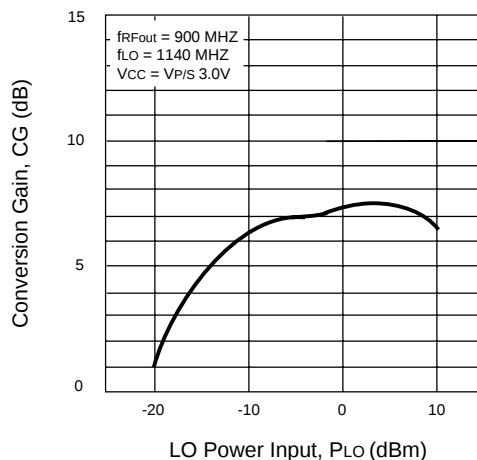


TYPICAL PERFORMANCE CURVES (TA = 25°C)

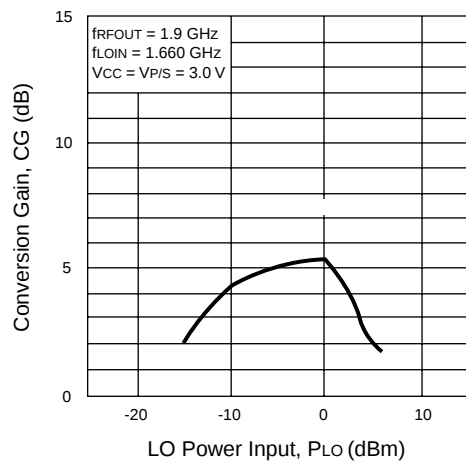
CONVERSION GAIN vs.
VOLTAGE AND FREQUENCY



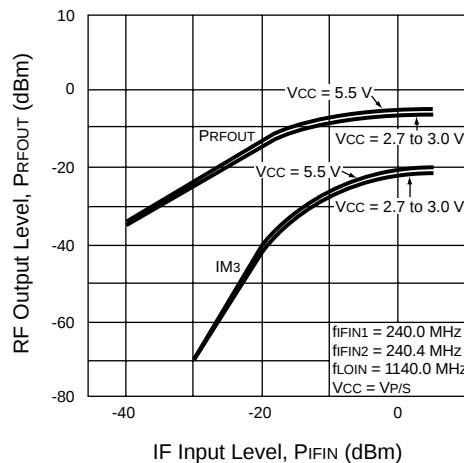
CONVERSION GAIN vs. INPUT LEVEL
AT RF = 900 MHz



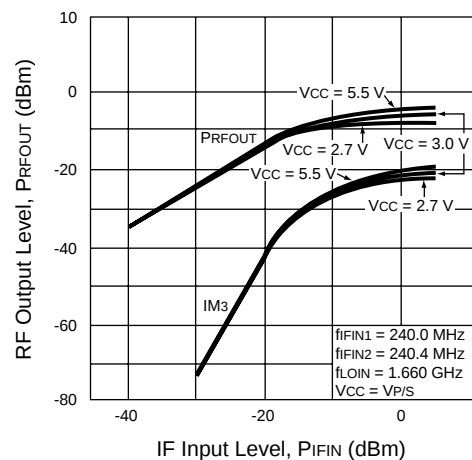
CONVERSION GAIN vs. INPUT LEVEL
AT RF = 1.9 GHz



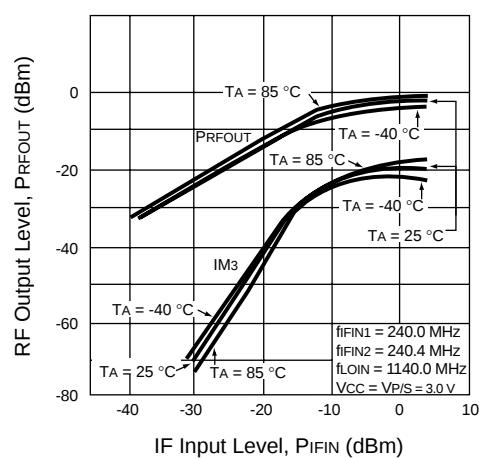
IM₃ AND RF OUTPUT LEVEL vs. IF INPUT LEVEL
AND VOLTAGE AT RF = 900 MHz



IM₃ AND RF OUTPUT LEVEL vs. IF INPUT LEVEL
AND VOLTAGE AT RF = 1.9 GHz

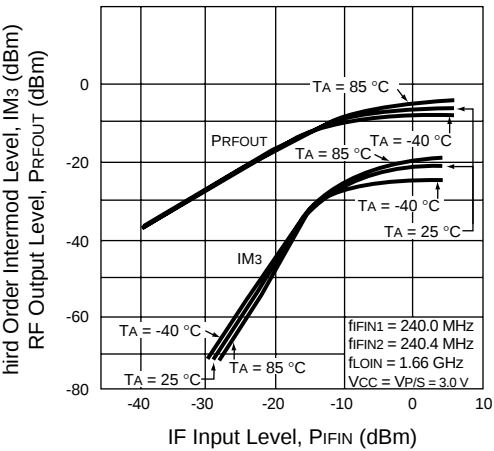


IM₃ AND RF OUTPUT LEVEL vs. IF INPUT LEVEL
AND TEMPERATURE AT RF = 900 MHz

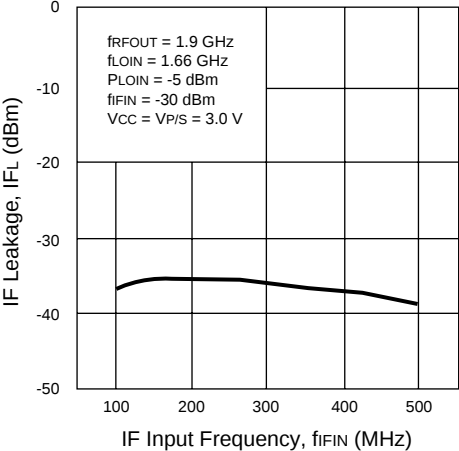


TYPICAL PERFORMANCE CURVES (TA = 25°C)

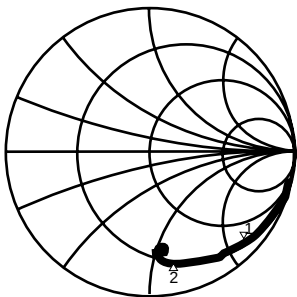
IM3 AND RF OUTPUT LEVEL vs. IF INPUT LEVEL
AND TEMPERATURE AT RF = 1.9 GHz



IF LEAKAGE AT RF PIN vs.
IF INPUT FREQUENCY AT RF = 1.9 GHz



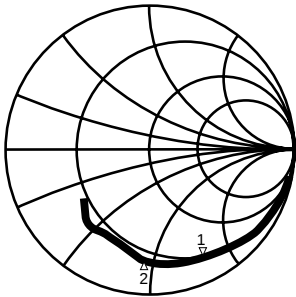
S11 - RF OUTPUT PORT



Start 500 MHz Stop 2300 MHz

2: 13.845 Ω -77.34 Ω 1.0850 pF
1: 20.633 Ω -144.74 Ω 1.2218 pF
Marker 1 - 900 MHz
Marker 2 - 1.9 GHz

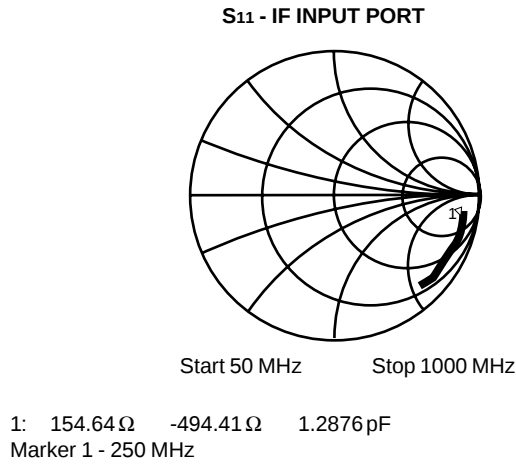
S11 - LO INPUT PORT



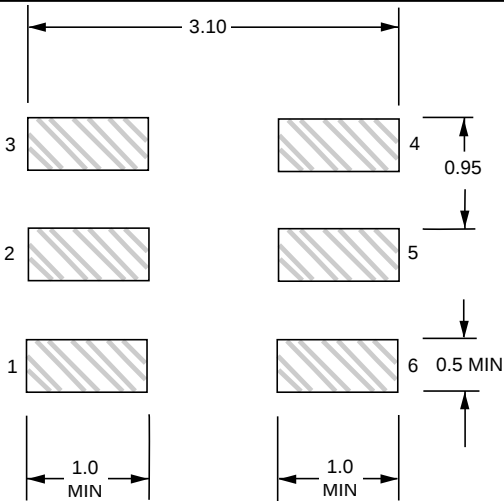
Start 0.3 MHz Stop 3000 MHz

2: 12.050 Ω -45.695 Ω 2.1780 pF
1: 13.961 Ω -76.158 Ω 1.8332 pF
Marker 1 - 1.14 GHz
Marker 2 - 1.66 GHz

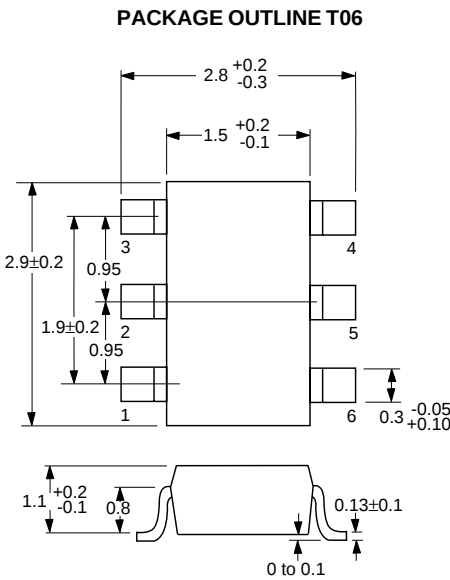
TYPICAL PERFORMANCE CURVES (TA = 25°C)



RECOMMENDED P.C.B. LAYOUT (Units in mm)

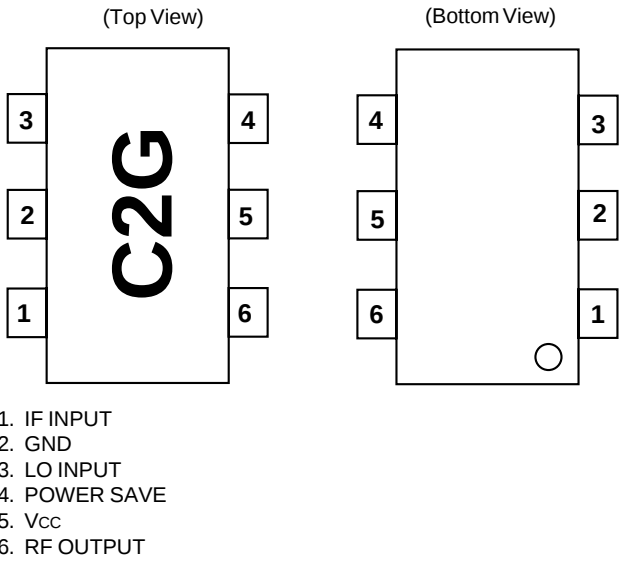


OUTLINE DIMENSIONS (Units in mm)



Note:
All dimensions are typical unless otherwise specified.

LEAD CONNECTIONS



ORDERING INFORMATION

PART NUMBER	QTY
UPC8109T-E3	3K/Reel

Note:
Embossed Tape, 8 mm wide,
Pins 1, 2, 3 are in tape pull-out direction.